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IGBT

FGA50N60LS

General Description

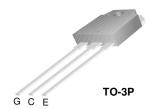
Fairchild's LS series product of Insulated Gate Bipolar Transistors (IGBTs) provides low conduction and switching losses as well as short circuit ruggedness. The LS series is especially designed for applications in medium frequencies such as switched reluctance motor controls, AC & DC motor controls, general inverters etc.

Features

- Short circuit rated 10 μ s @ T_C = 100°C, V_{GE} = 15V Low saturation voltage : V_{CE(sat)} = 1.6 V @ I_C = 50A
- · High input impedance
- Optimized for medium operating frequencies (1~5kHz)

Applications

Switched Reluctance Motor Controls, AC & DC motor controls, general purpose inverters, Robotics, and Servo controls





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

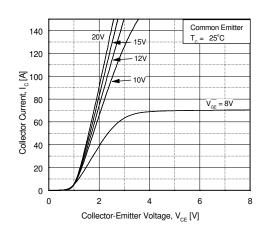
Symbol	Description		FGA50N60LS	Units
V _{CES}	Collector-Emitter Voltage		600	V
V _{GES}	Gate-Emitter Voltage		± 20	V
	Collector Current	@ T _C = 25°C	100	Α
IC	Collector Current	@ T _C = 100°C	50	Α
I _{CM (1)}	Pulsed Collector Current		150	Α
T _{SC}	Short Circuit Withstand Time	@ T _C = 100°C	10	μs
P_{D}	Maximum Power Dissipation	@ $T_C = 25^{\circ}C$	240	W
	Maximum Power Dissipation	@ T _C = 100°C	96	W
TJ	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		0.52	°C/W
$R_{\theta JA}$			40	°C/W

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Chai	racteristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	$V_{GE} = 0V, I_{C} = 250uA$	600			V
$\Delta B_{VCES}/$ ΔT_{J}	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0V$, $I_C = 1mA$		0.6		V/°C
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$			250	uA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$			± 100	nA
	racteristics					
V _{GE(th)}	G-E Threshold Voltage	$I_C = 50$ mA, $V_{CE} = V_{GE}$	3.5	5.5	7.5	V
• GE(tn)	Collector to Emitter	$I_C = 50A$, $V_{GE} = 15V$		1.6	1.8	V
V _{CE(sat)}	Saturation Voltage	$I_C = 80A$, $V_{GE} = 15V$		1.96		V
		1 10 0071, TGE 101				
Dynami	c Characteristics					
C _{ies}	Input Capacitance	$V_{CE} = 30V_{.}V_{GE} = 0V_{.}$		2660		рF
C _{oes}	Output Capacitance	f = 1MHz		250		рF
C _{res}	Reverse Transfer Capacitance			78		рF
t _{d(on)}	ng Characteristics Turn-On Delay Time			54		ns
t _r	Rise Time	-		96		ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 300 \text{ V}, I_{C} = 50\text{A},$		146	220	ns
<u>'α(οπ)</u> t _f	Fall Time	$R_G = 5.9\Omega, V_{GE} = 15V,$		326	600	ns
E _{on}	Turn-On Switching Loss	Inductive Load, $T_C = 25^{\circ}C$		1.1		mJ
E _{off}	Turn-Off Switching Loss			3.2		mJ
<u>-οπ</u> E _{ts}	Total Switching Loss	-		4.3	6.0	mJ
t _{d(on)}	Turn-On Delay Time			56		ns
t _r	Rise Time	-		87		ns
	Turn-Off Delay Time	$V_{CC} = 300 \text{ V}, I_{C} = 50 \text{A},$		134	215	ns
t _{d(off)} t _f	Fall Time	$R_G = 5.9\Omega, V_{GE} = 15V,$		575	880	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 125°C		1.2		mJ
E _{off}	Turn-Off Switching Loss	1		5.0		mJ
E _{ts}	Total Switching Loss	1		6.2	8.7	mJ
T _{sc}	Short Circuit Withstand Time	V _{CC} =300 V, V _{GE} = 15V @ T _C = 100°C	10			μs
Q _a	Total Gate Charge			167	240	nC
Q_ge	Gate-Emitter Charge	$V_{CE} = 300 \text{ V}, I_{C} = 50 \text{A},$		27	35	nC
Q _{gc}	Gate-Collector Charge	V _{GE} = 15V		68	100	nC



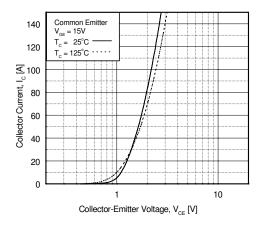
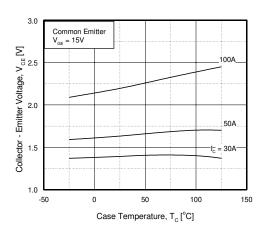


Fig 1. Typical Output Characteristics

Fig 2. Typical Saturation Voltage Characteristics



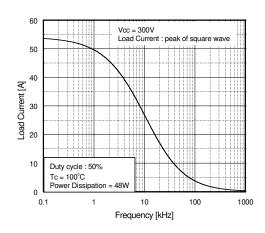
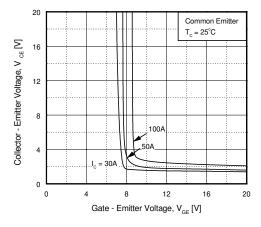


Fig 3. Saturation Voltage vs. Case Temperature at Variant Current Level

Fig 4. Load Current vs. Frequency



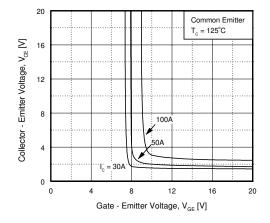
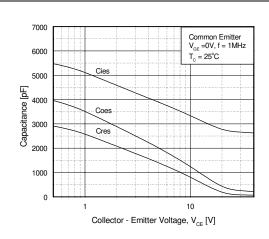


Fig 5. Saturation Voltage vs. V_{GE}

Fig 6. Saturation Voltage vs. V_{GE}

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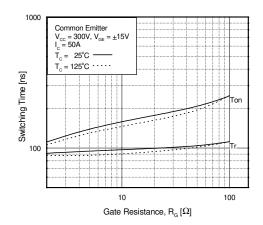
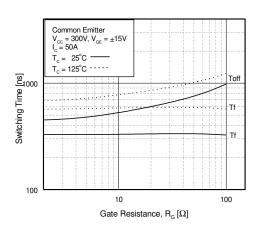


Fig 7. Capacitance Characteristics

Fig 8. Turn-On Characteristics vs.
Gate Resistance



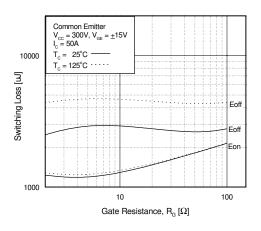
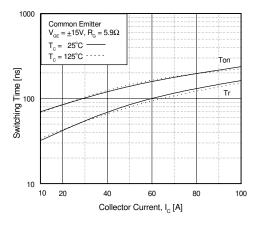


Fig 9. Turn-Off Characteristics vs.
Gate Resistance

Fig 10. Switching Loss vs. Gate Resistance



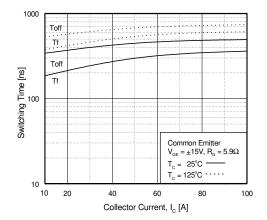
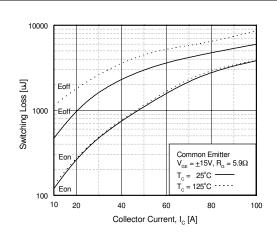


Fig 11. Turn-On Characteristics vs. Collector Current

Fig 12. Turn-Off Characteristics vs. Collector Current



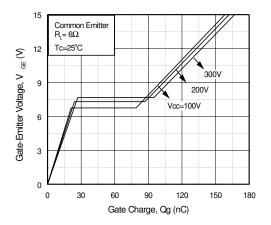
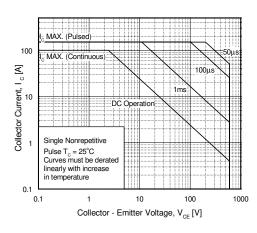


Fig 13. Switching Loss vs. Collector Current

Fig 14. Gate Charge Characteristics



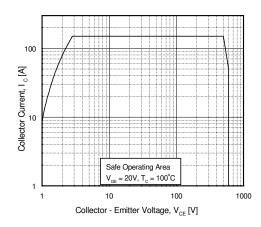


Fig 15. SOA Characteristics

Fig 16. Turn-Off SOA

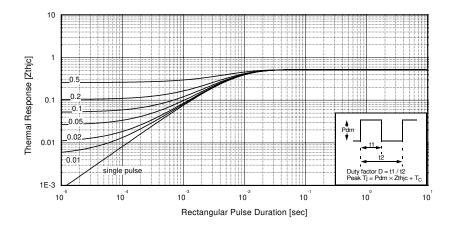
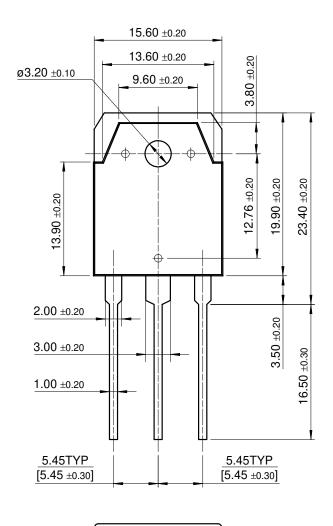
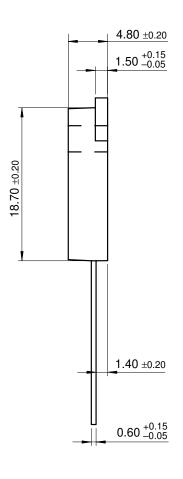


Fig 17. Transient Thermal Impedance of IGBT



TO-3P







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